Preliminary Data Sheet



COC 2.5mm PRELIMINARY

High Power SemiNex Lasers 12xx to 19xx nm Custom Wavelengths Available

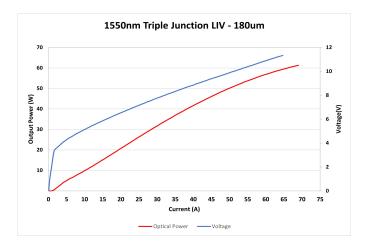
Applications

- OEM Medical
 Telecom/OTDR
- DPSS pump source
- LiDAR
 Military / Aerospace

- Features Cost effective High Output Power High Efficiency Standard Package

SemiNex delivers the highest available power at infrared wavelengths between 12xx and 19xx nm. When necessary we will further optimize the design of our InP laser chips to meet our customers' specific optical and electrical performance needs. Diodes, bars and packages are tested to meet customer and market performance demands. Typical results and packaging options are shown. Contact SemiNex for additional details or to discuss your specific requirements.





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PI Sheet

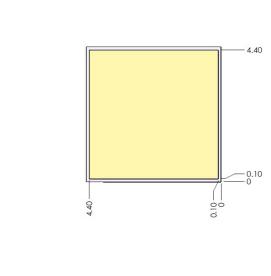


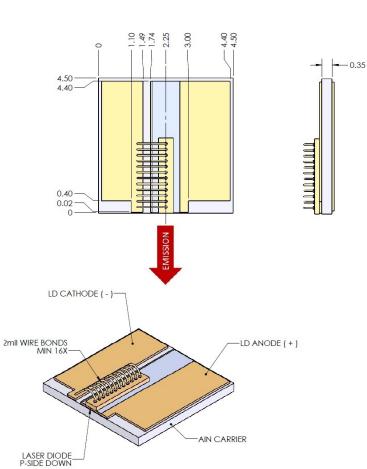




	Symbol	COC-266	Units
Optical			
Vavelength	λ _c	1550	nm (±20)
Dutput Power (<10ns)	P°	80.00	watts (±10%)
Duput Power (150ns)	P°	52.00	watts (±10%)
Chip Cavity Length	CL	2500	μm
Emitter Width	W	180	μm
Emitter Height	Н	10	μm
Spectral Width	δλ	22	nm 3dB
Slope Efficiency	Ŋ۰	0.90	W/A
ast Axis Div.*	O_perp	28	deg FWHM
Slow Axis Div.	Θ_parallel	12	deg FWHM
Electrical			
Power Conversion Eff.	η	8	%
hreshold Current	l _{th}	1	A
Operating Current (<10ns)	I _{op}	90	A
Operating Current (150ns)	I _{op}	56	A
Dperating Voltage	V _{op}	11	V
/lechanical			
Veight		0.05	g
Dperating Temp.**		-40 to 85	°C
Storage Temp.		-40 to 85	°C

Specified values are rated at a constant heat sink temperature of 20°C. **Specified operating conditions are based on 20C heat sink temperature. High temperature operation will reduce performance and MTTF. Unless otherwise indicated all values are nominal.





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SemiNex Corporation • 153 Andover St • Danvers, MA 01923 • 978-326-7700 • Email: info@seminex.com • www.seminex.com

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